

HD74HCT125, HD74HCT126

Quad. Bus Buffer Gates (with 3-state outputs)

REJ03D0657-0200 (Previous ADE-205-545) Rev.2.00 Mar 30, 2006

Description

The HD74HCT125, HD74HCT126 require the 3-state control input C to be taken high to put the output into the high impedance condition, whereas the HD74HCT125, HD74HCT126 requires the control input to be low to put the output into high impedance.

Features

• LSTTL Output Logic Level Compatibility as well as CMOS Output Compatibility

• High Speed Operation: t_{pd} (A to Y) = 12 ns typ ($C_L = 50 \text{ pF}$)

• High Output Current: Fanout of 15 LSTTL Loads

• Wide Operating Voltage: $V_{CC} = 4.5$ to 5.5 V

• Low Input Current: 1 μA max

• Low Quiescent Supply Current: I_{CC} (static) = 4 μ A max (Ta = 25°C)

• Ordering Information

Part Name	Package Type	Package Code (Previous Code)	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74HCT125P	DILP-14 pin	PRDP0014AB-B	Р	_	
HD74HCT125FPEL		(DP-14AV) PRSP0014DF-B		+	
HD74HCT126FPEL	SOP-14 pin (JEITA)	(FP-14DAV)	FP	EL (2,000 pcs/reel)	
HD74HCT125TELL	TSSOP-14 pin	PTSP0014JA-B	т	ELL (2,000 pcs/reel)	
HD74HCT126TELL	1330F-14 pili	(TTP-14DV)	ı	ELL (2,000 pcs/reei)	

Note: Please consult the sales office for the above package availability.

Function Table

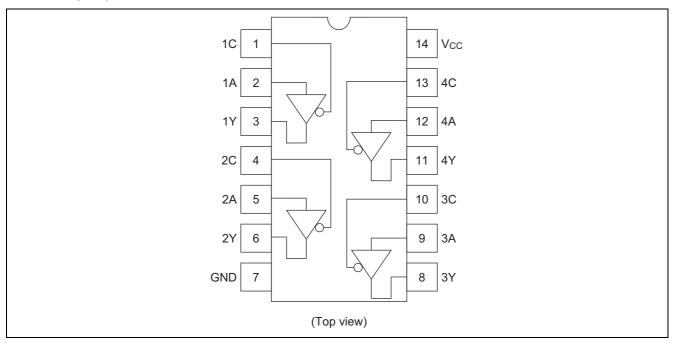
	Inputs	Output		
	С	Α	,	Υ
HCT125	HCT125 HCT126		HCT125	HCT126
Н	L	X	Z	Z
L	Н	L	L	L
L	Н	Н	Н	Н

H: High levelL: Low levelX: Irrelevant

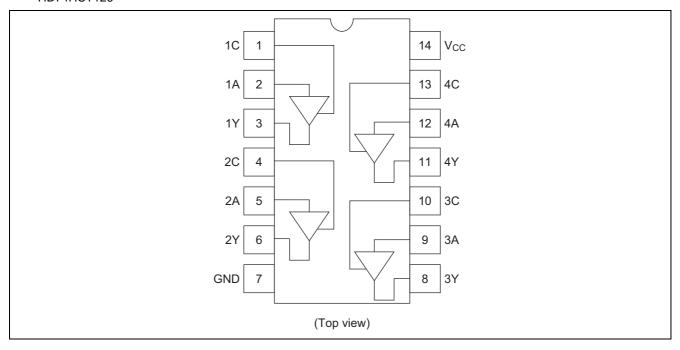
Z: Off (high-impedance) state of a 3-state output.

Pin Arrangement

• HD74HCT125



• HD74HCT126



Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	V _{CC}	−0.5 to +7.0	V
Input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
Output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Output current	I _{OUT}	±35	mA
DC current drain per V _{CC} , GND	I _{CC} , I _{GND}	±75	mA
DC input diode current	I _{IK}	±20	mA
DC output diode current	I _{OK}	±20	mA
Power dissipation per package	P _T	500	mW
Storage temperature	Tstg	-65 to +150	°C

Note: The absolute maximum ratings are values, which must not individually be exceeded, and furthermore, no two of which may be realized at the same time.

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Conditions
Supply voltage	V_{CC}	4.5 to 5.5	V	
Input / Output voltage	V_{IN}, V_{OUT}	0 to V _{CC}	V	
Operating temperature	Та	-40 to 85	°C	
Input rise / fall time*1	t _r , t _f	0 to 500	ns	V _{CC} = 4.5 V

Notes: 1. This item guarantees maximum limit when one input switches.

Waveform: Refer to test circuit of switching characteristics.

Electrical Characteristics

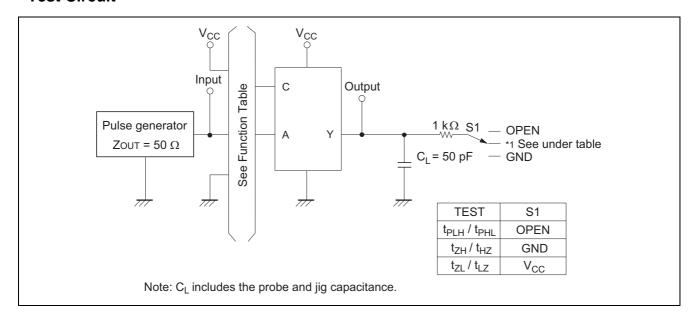
Item	Symbol	V (\(\)	T	a = 25°	С	Ta = -40	to+85°C	Unit	Test Conditions	
item	Syllibol	V _{CC} (V)	Min	Тур	Max	Min	Max	Oilit	lest con	iuitions
Input voltage	V _{IH}	4.5 to 5.5	2.0	_	_	2.0	_	V		
	V _{IL}	4.5 to 5.5	_	_	0.8	_	0.8	V		
Output voltage	V _{OH}	4.5	4.4	_	_	4.4	_	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -20 \mu A$
		4.5	4.18	_	_	4.13	_			$I_{OH} = -6 \text{ mA}$
	V _{OL}	4.5	_	_	0.1	_	0.1	V	$Vin = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 20 \mu A$
		4.5	_	_	0.26	_	0.33			$I_{OL} = 6 \text{ mA}$
Off-state output	l _{OZ}	5.5	_	_	±0.5	_	±5.0	μΑ	$Vin = V_{IH} \text{ or } V_{IL},$	
current									Vout = V_{CC} or G	ND
Input current	lin	5.5	l	_	±0.1	_	±1.0	μΑ	$Vin = V_{CC}$ or GN	D
Quiescent supply	I _{CC}	5.5	_	_	4.0	_	40	μΑ	$Vin = V_{CC}$ or GND, $Iout = 0$	
current										

Switching Characteristics

 $(C_L = 50 \text{ pF, Input } t_r = t_f = 6 \text{ ns})$

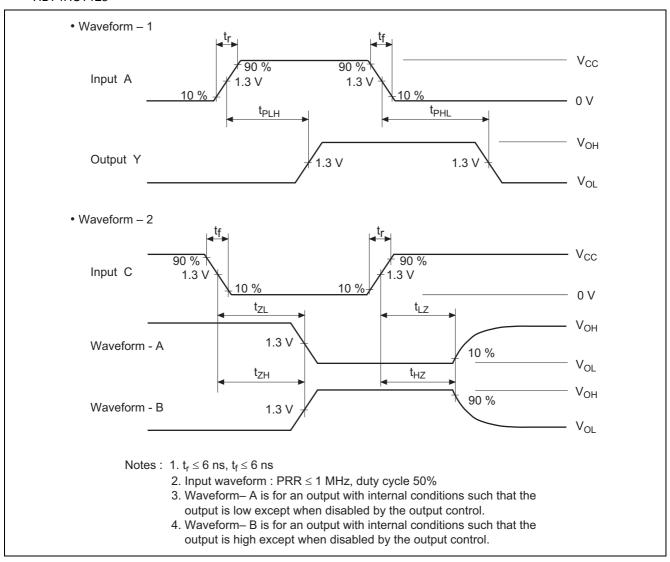
Item	Symbol V _{CC} (V)		Ta = 25°C			Ta = -40 to +85°C		Unit	Test Conditions
item	Symbol	VCC (V)	Min	Тур	Max	Min	Max	Onit	rest Conditions
Propagation delay time	t _{PHL}	4.5	_	12	20	_	25	ns	
	t _{PLH}	4.5	_	12	20	_	25		
Output enable time	t _{ZL}	4.5	1	12	30	_	38	ns	
	t _{zH}	4.5	l	12	30	_	38		
Output disable time	t _{LZ}	4.5	l	15	30	_	38	ns	
	t _{HZ}	4.5	l	15	30	_	38		
Output rise/fall time	t _{TLH}	4.5	1	4	12	_	15	ns	
	t _{THL}	4.5		4	12	_	15		
Input capacitance	Cin	_	_	5	10	_	10	pF	

Test Circuit



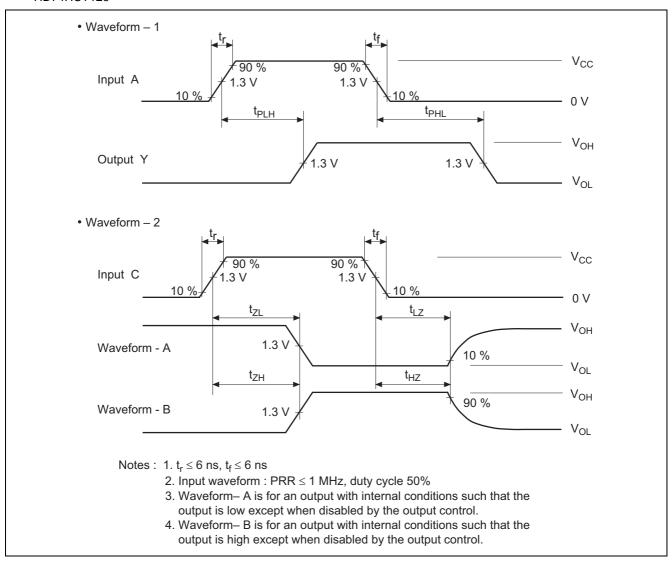
Waveforms

HD74HCT125

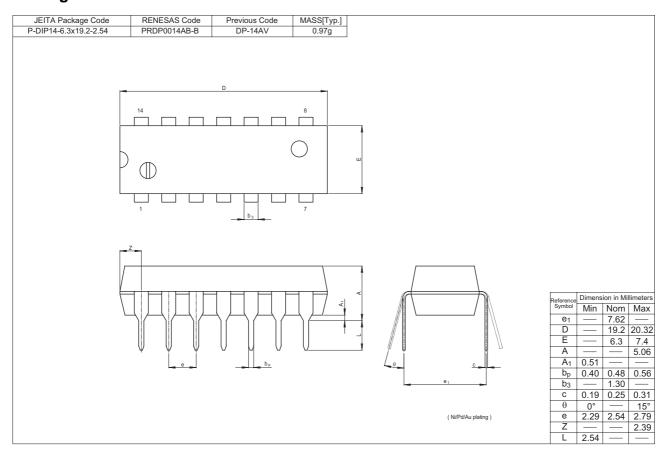


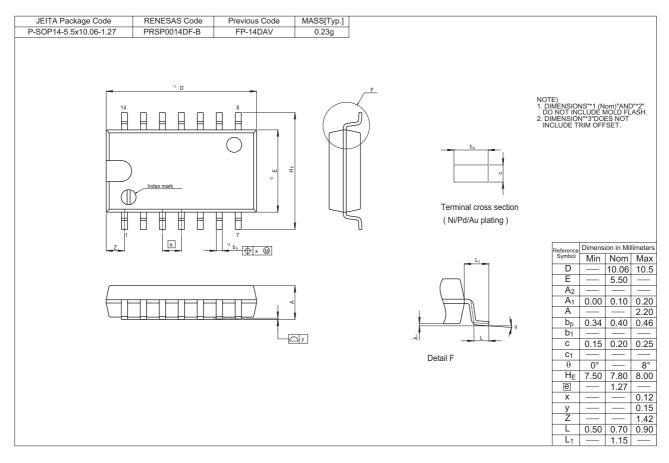
Waveforms

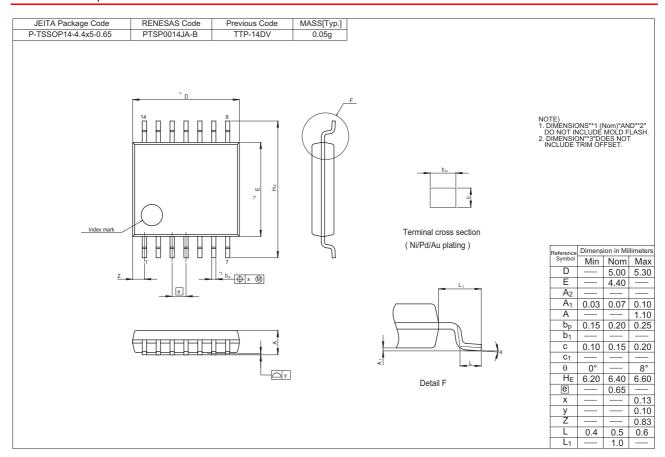
HD74HCT126



Package Dimensions







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